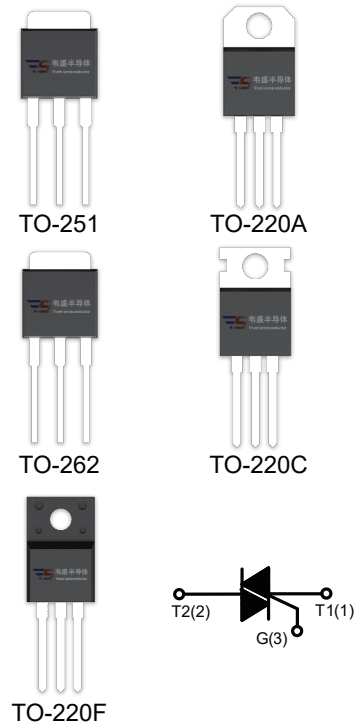


DESCRIPTION:

The BT137-600E SCR series with the parallel resistor between Gate and Cathode are especially recommended for use on straight hair, igniter, anion generator, etc.


MAIN FEATURES

| Symbol | Value | Unit |
|-------------------|-------------|------|
| $I_{T(RMS)}$ | 8 | A |
| V_{DRM}/V_{RRM} | 600 and 800 | V |

ABSOLUTE MAXIMUM RATINGS

| Parameter | Symbol | Value | Unit |
|--|--|---------|----------------------|
| Storage junction temperature range | T_{stg} | -40-150 | °C |
| Operating junction temperature range | T_j | -40-125 | °C |
| Repetitive peak off-state voltage($T_j=25^\circ\text{C}$) | V_{DRM} | 600/800 | V |
| Repetitive peak reverse voltage($T_j=25^\circ\text{C}$) | V_{RRM} | 600/800 | V |
| RMS on-state current | TO-251/ TO-220A(Non-Ins)/ TO-220C($T_C=95^\circ\text{C}$) | 8 | A |
| | TO-262/ TO-220A(Ins)/ TO-220F(Ins) ($T_C=85^\circ\text{C}$) | | |
| Non repetitive surge peak on-state current (full cycle, F=50Hz) | I_{TSM} | 65 | A |
| I^2t value for fusing ($t_p=10\text{ms}$) | I^2t | 21 | A^2s |
| Peak gate current | I_{GM} | 2 | A |

| | | | | |
|--|-------------|-------------|-----|------------|
| Critical rate of rise of on-state current($I_G=2 \times I_{GT}$) | I - II -III | di/dt | 50 | A/ μ s |
| | IV | | 10 | |
| Average gate power dissipation | | $P_{G(AV)}$ | 0.5 | W |
| Peak gate power | | P_{GM} | 5 | W |

ELECTRICAL CHARACTERISTICS ($T_j=25^\circ\text{C}$ unless otherwise specified)

| Symbol | Test Condition | Quadrant | Value | | | | Unit | |
|----------|--|-------------|-------|-----|----|----|------|------------|
| | | | D | E | F | G | | |
| I_{GT} | $V_D=12\text{V}$ $R_L=30\Omega$ | I - II -III | MAX | 5 | 10 | 25 | 50 | mA |
| | | IV | | 10 | 25 | 70 | 100 | |
| V_{GT} | | ALL | MAX | 1.3 | | | | V |
| V_{GD} | $V_D=V_{DRM}$ $T_j=125^\circ\text{C}$ $R_L=3.3\text{K}\Omega$ | ALL | MIN | 0.2 | | | | V |
| I_L | $I_G=1.2I_{GT}$ | I - III | MAX | 10 | 20 | 50 | 70 | mA |
| | | II - IV | | 20 | 30 | 70 | 100 | |
| I_H | $I_T=100\text{mA}$ | | MAX | 10 | 15 | 40 | 60 | mA |
| dV/dt | $V_D=2/3V_{DRM}$ Gate Open $T_j=125^\circ\text{C}$ | | MIN | 20 | 50 | 50 | 200 | V/ μ s |

STATIC CHARACTERISTICS

| Symbol | Parameter | | Value(MAX) | Unit |
|-----------|--|-------------------------|------------|---------------|
| V_{TM} | $I_{TM}=10\text{A}$ $t_p=380\mu\text{s}$ | $T_j=25^\circ\text{C}$ | 1.6 | V |
| I_{DRM} | $V_D=V_{DRM}$ $V_R=V_{RRM}$ | $T_j=25^\circ\text{C}$ | 5 | μA |
| I_{RRM} | | $T_j=125^\circ\text{C}$ | 1 | mA |

THERMAL RESISTANCES

| Symbol | Parameter | | Value | Unit |
|---------------|----------------------|-------------------------------|-------|--------------------|
| $R_{th(j-c)}$ | junction to case(AC) | TO-251 | 2.1 | $^\circ\text{C/W}$ |
| | | TO-220A(Non-Ins)/ TO-220C | 1.8 | |
| | | TO-220A(Ins)/ TO-220F(Ins) | 2.9 | |
| | | TO-262 | 3.1 | |

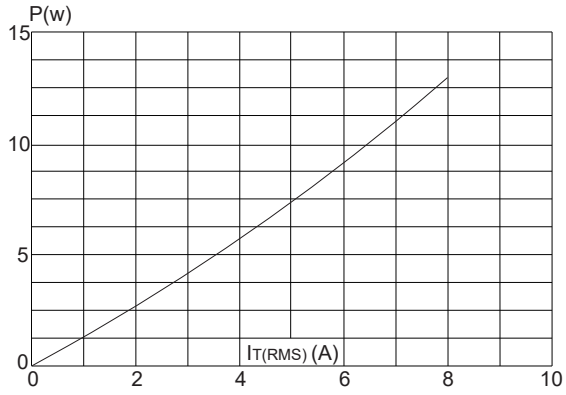
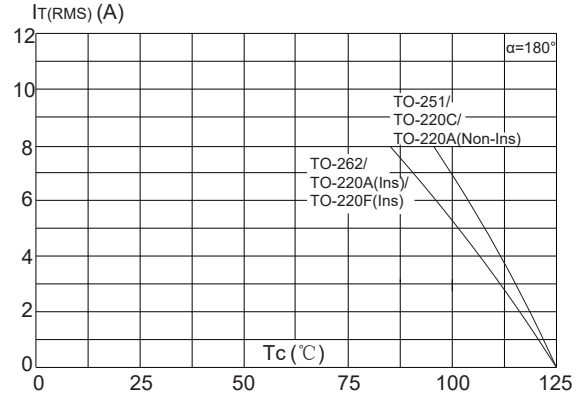
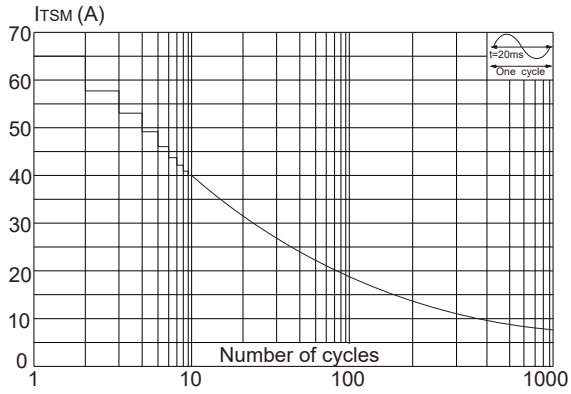
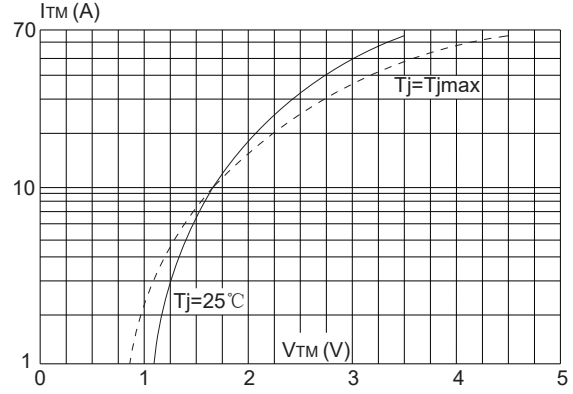
FIG.1: Maximum power dissipation versus RMS on-state current

FIG.2: RMS on-state current versus case temperature

FIG.3: Surge peak on-state current versus number of cycles

FIG.4: On-state characteristics (maximum values)


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 20\text{ms}$, and corresponding value of I^2t (I - II -III: $dI/dt < 50\text{A}/\mu\text{s}$; IV: $dI/dt < 10\text{A}/\mu\text{s}$)

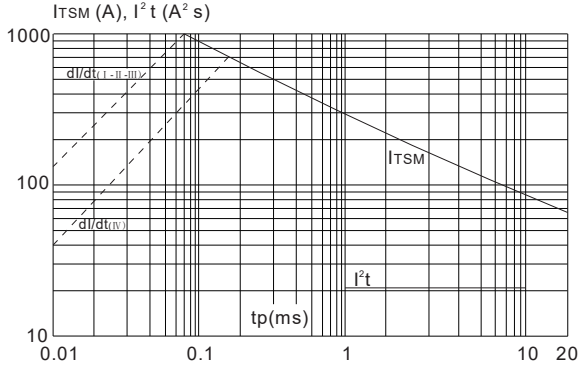


FIG.7: Relative variations of holding current versus junction temperature

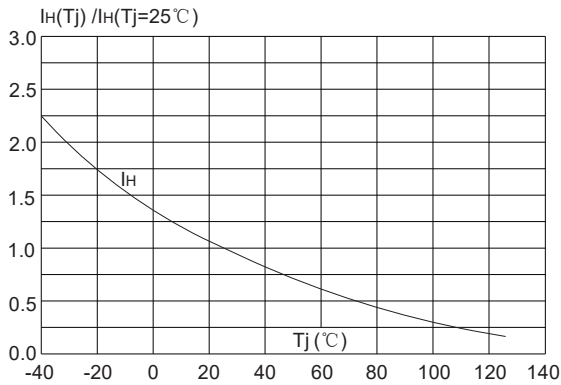


FIG.6: Relative variations of gate trigger current versus junction temperature

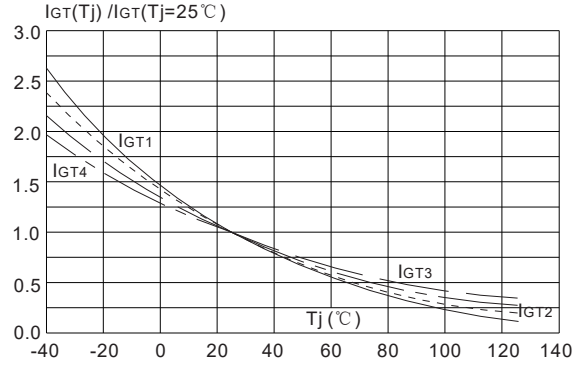


FIG.8: Relative variations of latching current versus junction temperature

